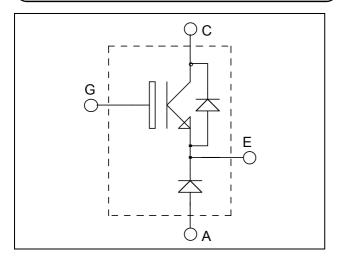


APT40GL120JU3

ISOTOP[®] Buck chopper Trench + Field Stop IGBT4 Power module





$V_{CES} = 1200V$ $I_{C} = 40A$ @ Tc = 80°C

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
 - ISOTOP[®] Package (SOT-227)
- Very low stray inductance
- High level of integration

Benefits

- Low conduction losses
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Breakdown Voltage		1200	V
I _C	Continuous Collector Current	$T_C = 25^{\circ}C$	65	
	T _d	$T_C = 80^{\circ}C$	40	А
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	70	
V _{GE}	Gate – Emitter Voltage		±20	V
P _D	Maximum Power Dissipation	$T_C = 25^{\circ}C$	220	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	70A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics								
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μA	
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.85	2.25	V	
		$I_{\rm C} = 35 {\rm A}$ $T_{\rm j} = 150^{\circ} {\rm C}$		2.25		v		
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1.2 \text{mA}$		5.0	5.8	6.5	V	
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA	

Dynamic Characteristics

 $\mathbf{\alpha}$

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			1950		
Coes	Output Capacitance				155		pF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz			115		
Q _G	Gate charge	$V_{GE} = \pm 15V$; $V_{CE} = 600V$ $I_{C} = 35A$			0.27		μC
T _{d(on)}	Turn-on Delay Time	Inductive Switc	hing (25°C)		130		
T _r	Rise Time	$V_{GE} = \pm 15V$			20		
T _{d(off)}	Turn-off Delay Time	$V_{CE} = 600V$ $I_C = 35A$ $R_G = 12\Omega$			300		ns
T _f	Fall Time				45		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_C = 35A$			150		ns
T _r	Rise Time				35		
T _{d(off)}	Turn-off Delay Time				350		
T _f	Fall Time	$R_G = 12\Omega$			80		
Eon	Turn on Switching Energy	$V_{GE} = \pm 15V$ $V_{CE} = 600V$	$T_J = 25^{\circ}C$		2.6		mI
Lon	Turn-on Switching Energy		$T_{\rm J} = 150^{\circ}{\rm C}$		4		mJ
E _{off}	Turn-off Switching Energy	$I_{\rm C} = 35 \text{A}$	$T_J = 25^{\circ}C$		2		mJ
Loff	Turn-on Ownening Litergy	$R_G = 12\Omega$	$T_{\rm J} = 150^{\circ}{\rm C}$		3		1115
I _{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10\mu s$; $T_j = 150^{\circ}C$			140		А

Chopper diode ratings and characteristics

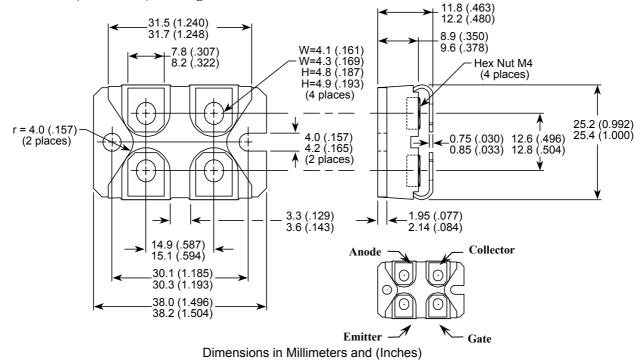
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I _{RM}	Maximum Reverse Leakage Current V _R =	V _R =1200V	$T_j = 25^{\circ}C$			100	۸
IRM		v _R -1200 v	$V_{\rm R}$ = 1200 V $T_{\rm j}$ = 150°C			500	μA
I _F	DC Forward Current		$Tc = 80^{\circ}C$		30		Α
	Diode Forward Voltage	$I_F = 30A$			2.6	3.1	
$V_{\rm F}$		$I_F = 60A$			3.2		V
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		1.8		
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		300		ns
ι _{TT}	Reverse Recovery Time	$I_F = 30A$ $V_R = 800V$	$T_{j} = 125^{\circ}C$		380		115
0	Reverse Recovery Charge	$v_R = 300 v$ di/dt =200A/µs	$T_j = 25^{\circ}C$		360		nC
Q _{rr}	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		1700		ne



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R _{thJC}	Junction to Case Thermal Resistance IGBT Diode	IGBT			0.68	°C/W	
		Diode			1.2		
R _{thJA}	Junction to Ambient (IGBT & Diode)				20		
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		2500			V	
T_J, T_{STG}	Storage Temperature Range		-55		175	°C	
$T_{\rm L}$	Max Lead Temp for Soldering:0.063" from case for 10 sec				300	C	
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m	
Wt	Package Weight			29.2		g	

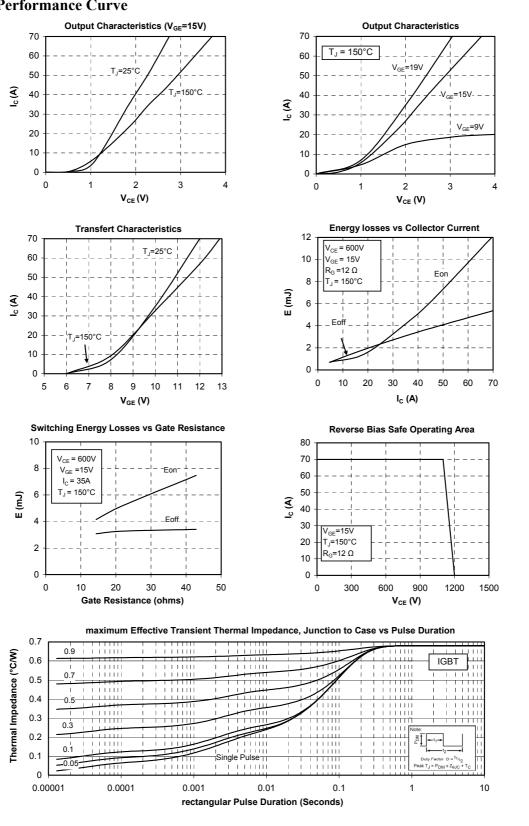
SOT-227 (ISOTOP[®]) Package Outline



ISOTOP® is a registered trademark of ST Microelectronics NV



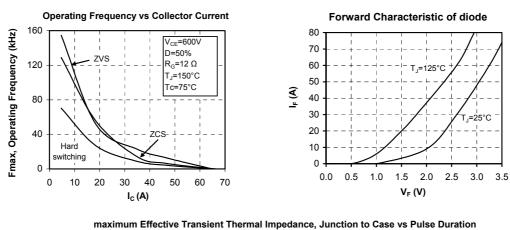
Typical Performance Curve

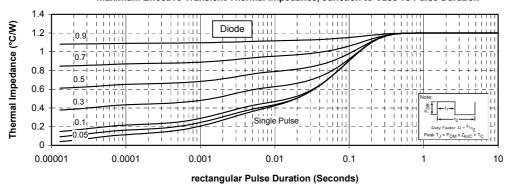


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